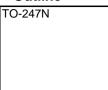


SCT4062KE

N-channel SiC power MOSFET

V _{DSS}	1200V
R _{DS(on)} (Typ.)	62mΩ
I_{D}^{*1}	26A
P _D	115W

Outline



Inner circuit



(1)(2(3)

Features

- 1) Low on-resistance
- 2) Fast switching speed
- 3) Fast reverse recovery
- 4) Easy to parallel
- 5) Simple to drive
- 6) Pb-free lead plating ; RoHS compliant

Application

- · Solar inverters
- DC/DC converters
- · Switch mode power supplies
- Induction heating

(1) 0 (1) 0 (1) 0 (1) 0 (1) Gate (2) Drain (3) Source *1 Body Diode	

Packaging specifications

	Packing	Tube
	Reel size (mm)	-
Tuno	Tape width (mm)	-
Туре	Basic ordering unit (pcs)	30
	Taping code	C11
	Marking	SCT4062KE

•Absolute maximum ratings (T_{vi} = 25°C unless otherwise specified.)

	,				
Parameter			Symbol	Value	Unit
Drain - source voltage		V _{DSS}	1200	V	
Continuous drain	$V_{GS} = V_{GS_{on}}$	$T_c = 25^{\circ}C$	ا _D , I _S ^{*1}	26	А
and source current	$v_{GS} = v_{GS_{on}}$	$T_c = 100^{\circ}C$	I _D , I _S	18	А
Pulsed drain current	$V_{GS} = V_{GS_{on}}$	$T_c = 25^{\circ}C$	I _{D,pulse} *2	52	А
Body diode pulsed forward current $T_c = 25^{\circ}C$		$T_c = 25^{\circ}C$	^{*1,*3} S,pulse	26	А
Body diode surge forward current		$V_{GS} = 0 V$	*1,*4 I _{S,pulse}	52	А
Gate - source voltage (DC)		$V_{GSS_{DC}}$	-4 to +21	V	
Gate - source surge volt	tage (t _{surge} < 300)ns)	V_{GSS_surge} *5	-4 to +23	V
Recommended turn-on	gate - source dr	ive voltage	V _{GS_on} *6	+15 to +18	V
Recommended turn-off gate - source drive voltage		V _{GS_off}	0	V	
Virtual junction temperature		T _{vj}	175	°C	
Range of storage temperature		T _{stg}	-40 to +175	°C	

•Electrical characteristics ($T_{vj} = 25^{\circ}C$ unless otherwise specified)

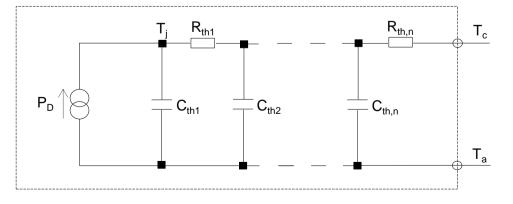
Deremeter	Cumphal	Conditiona		Unit		
Parameter	Symbol Conditions –		Min.	Тур.	Max.	Onit
Drain - Source breakdown	V	$V_{GS} = 0 V, I_{D} = 5.3 mA$				V
voltage	v (BR)DSS	$T_{vj} = 25^{\circ}C$	1200	-	-	v
		$V_{GS} = 0 V, V_{DS} = 1200V$				
Zero Gate voltage Drain current	I_{DSS}	T _{vj} = 25°C	-	1	80	μA
		T _{vj} = 150°C	-	10	-	
Gate - Source leakage current	I _{GSS+}	V_{GS} = +21V , V_{DS} = 0V	-	-	100	nA
Gate - Source leakage current		$V_{GS} = -4V$, $V_{DS} = 0V$	-	-	-100	nA
Gate threshold voltage	$V_{GS(th)}{}^{*7}$	$V_{DS} = 10V, I_{D} = 6.45mA$	2.8	-	4.8	V
		$V_{GS} = 18V, I_{D} = 12A$				
Static Drain - Source on - state resistance	R _{DS(on)} *8	T _{vj} = 25°C	-	62	81	mΩ
		T _{vj} = 150°C	-	124	-	
Gate input resistance	R_G	f = 1MHz, open drain	-	4	-	Ω

Thermal resistance

Paramotor	Symbol -	Values			Unit
Parameter		Min.	Тур.	Max.	Offic
Thermal resistance, junction - case	${\sf R_{thJC}}^{*9}$	-	0.98	1.3	K/W

•Typical Transient Thermal Characteristics

Symbol	Value	Unit	Symbol	Value	Unit
R _{th1}	8.4 ×10 ⁻²		C _{th1}	5.3 ×10 ⁻⁴	
R _{th2}	4.7 ×10 ⁻¹	K/W	C _{th2}	2.4 ×10 ⁻³	Ws/K
R _{th3}	4.2 ×10 ⁻¹		C _{th3}	4.3 ×10 ⁻²	





•Electrical characteristics (T_{vj} = 25°C unless otherwise specified)

		O	Symbol Conditions		Values		Unit	
Parameter		Symbol	Conditions	Min.	Тур.	Max.		
Transconducta	nce	g _{fs} *8	$V_{DS} = 10V, I_{D} = 12A$	-	6.5	-	S	
Input capacitan	се	C _{iss}	$V_{GS} = 0V$	-	1498	-		
Output capacita	ance	C _{oss}	V _{DS} = 800V	-	45	-	pF	
Reverse transfe	er capacitance	C _{rss}	f = 1MHz	-	3	-		
Effective outpu energy related	t capacitance,	C _{o(er)}	$V_{GS} = 0V$ $V_{DS} = 0V$ to 800V	-	54	-	pF	
Total Gate cha	rge	Q _g *8	$V_{DS} = 800V$ $I_{D} = 12A$	-	64	-		
Gate - Source	charge	Q _{gs} *8	$V_{GS} = 12A$ $V_{GS} = 18V$	-	14	-	nC	
Gate - Drain ch	arge	Q _{gd} *8	See Fig. 1-1, 1-2.	-	17	-		
Turn - on delay	time	t _{d(on)} *8	$V_{DS} = 800V$	-	6	-		
Rise time		t _r *8	I _D = 12A V _{GS} = +18V / 0V	-	20	-	20	
Turn - off delay	time	t _{d(off)} *8	$R_G = 0\Omega, L = 250\mu H$ E _{on} includes diode	-	25	-	ns	
Fall time		t _f *8	reverse recovery $L_{\sigma} = 50$ nH, $C_{\sigma} = 10$ pF	-	11	-		
Turn - on switc	hing loss	E _{on} *8	See Fig. 2-1, 2-2, 2-3.	-	250	-		
Turn - off switching loss		E _{off} *8		-	15	-	μJ	
Short-circuit	$V_{GS(on)} = +15V$	t _{sc} *9	V _{DS} ≤ 800V V _{DS,peak} ≤ 1200V	-	4.5	-	μs	
withstand time	$V_{GS(on)} = +18V$		$T_{vj(start)} = 25^{\circ}C$ $R_{G} = 2.2\Omega$	-	4.0	-	μs	



•Body diode electrical characteristics (Source-Drain) (T_{vi} = 25°C unless otherwise specified)

Doromotor	Symbol Conditions		Values			Linit
Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit
Forward voltage	V_{SD}^{*8}	$V_{GS} = 0V, I_S = 12A$	-	3.3	-	V
Reverse recovery time	t _{rr} *8	$I_F = 12A$ $V_R = 800V$	-	16	-	ns
Reverse recovery charge	Q _{rr} *8	di/dt = 2600A/µs	-	82	-	nC
Peak reverse recovery current	I _{rrm} *8	$L_{\sigma} = 50$ nH, $C_{\sigma} = 10$ pF See Fig. 3-1, 3-2.	-	10	-	А

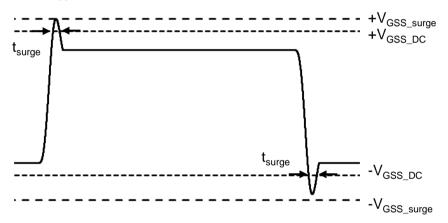
*1 Limited by maximum T_{vi} and for Max. R_{thJC} .

*2 Pulse width and duty cycle are limited by $T_{vj,max}$.

*3 Only for body-diode, Repititive pulse, PW \leq 1.5µs, Duty cycle \leq 5%

*4 When used as a protective function, PW \leq 10µs

*5 Example of acceptable V_{GS} waveform



- *6 Please be advised not to use SiC-MOSFETs with V_{GS} below 10V as doing so may cause thermal runaway.
- *7 Tested after applying V_{GS} = 21V for 100ms.
- *8 Pulsed
- *9 The value is based on TO-247 package. Single Pulsed.
- *10 Measured conformable to JESD51-14.

See the application note "rthjc_measurement_and_usage_an-e.pdf". Link

URL: https://fscdn.rohm.com/en/products/databook/applinote/discrete/common/rthjc_measurement_and_usage_an-e.pdf



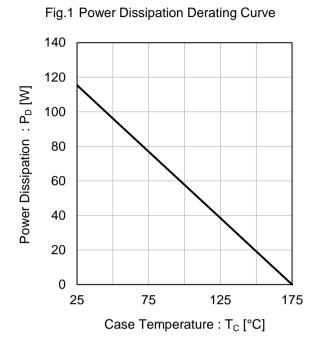


Fig.2 Maximum Safe Operating Area

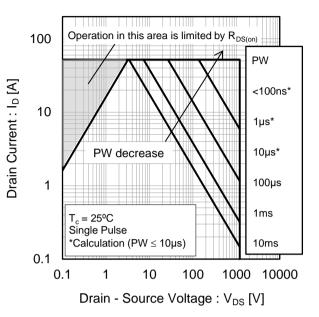
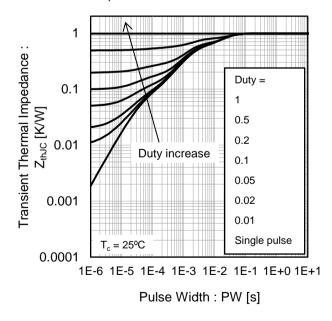
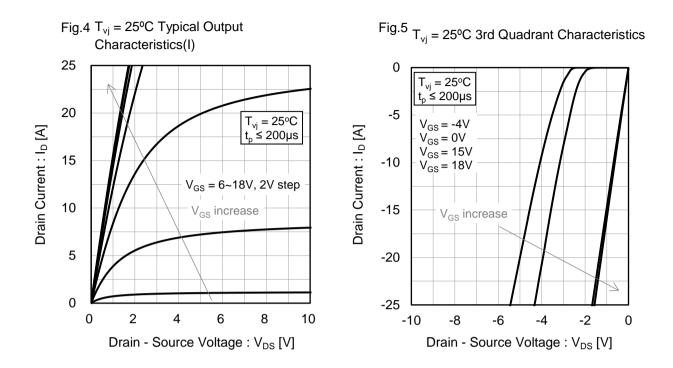


Fig.3 Typical Transient Thermal Impedance vs. Pulse Width

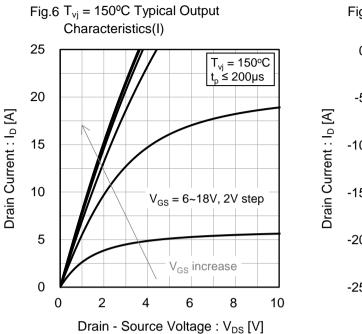


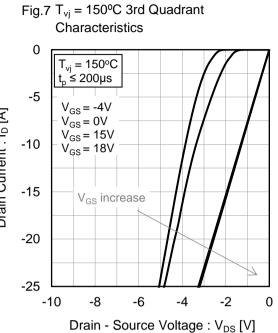
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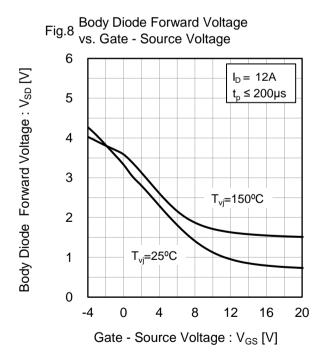














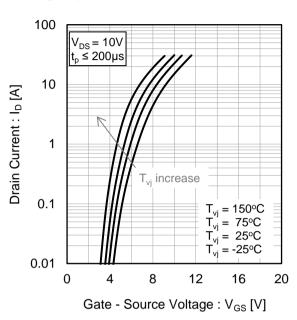
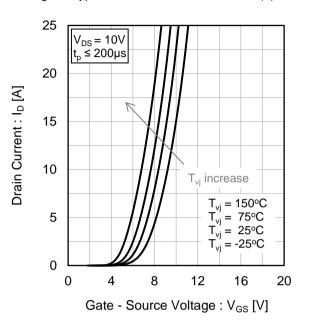


Fig.9 Typical Transfer Characteristics (I)

Fig.10 Typical Transfer Characteristics (II)



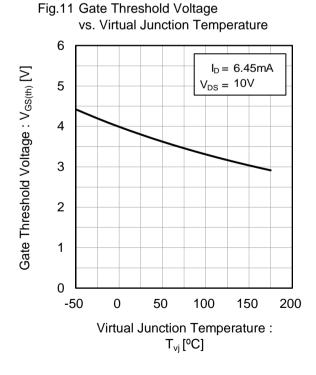
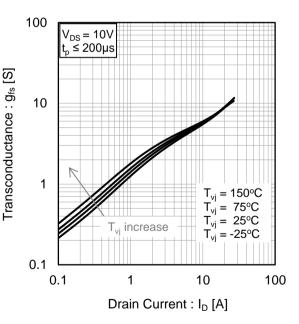
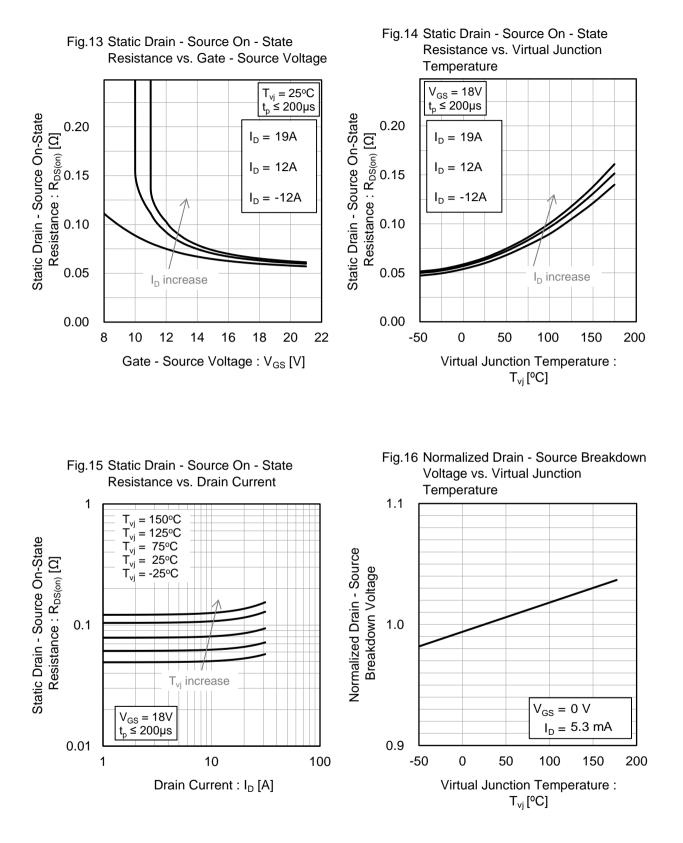


Fig.12 Transconductance vs. Drain Current









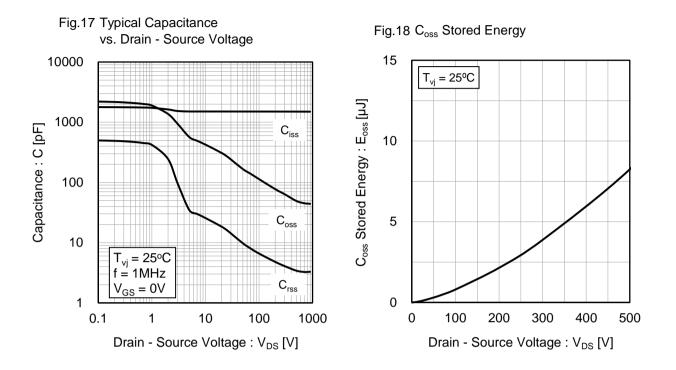
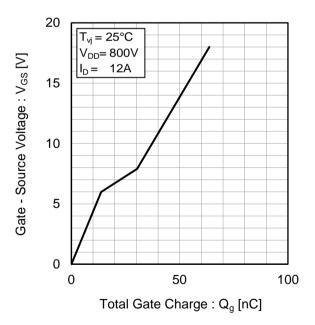
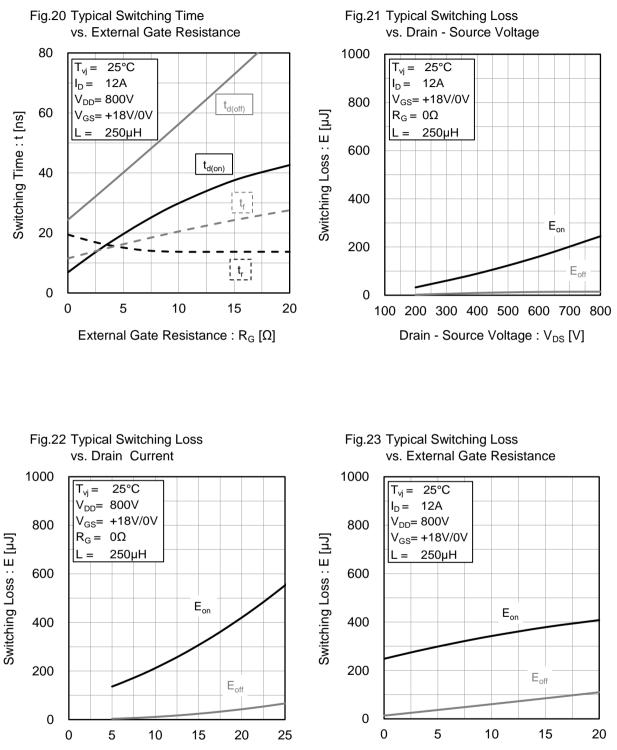


Fig.19 Dynamic Input Characteristics







External Gate Resistance : $R_G [\Omega]$

Drain Current : I_D [A]



Measurement circuits and waveforms

Fig.1-1 Gate Charge Measurement Circuit

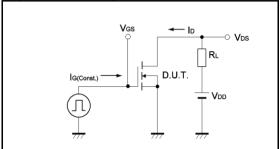


Fig.2-1 Switching Characteristics Measurement Circuit

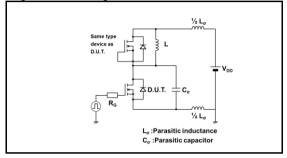


Fig.2-3 Waveforms for Switching Energy Loss

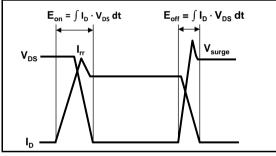


Fig.3-1 Reverse Recovery Time Measurement Circuit

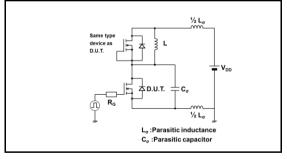


Fig.1-2 Gate Charge Waveform

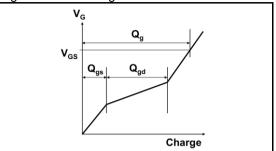


Fig.2-2 Waveforms for Switching Time

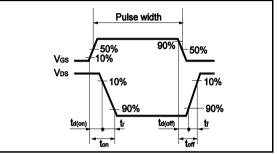
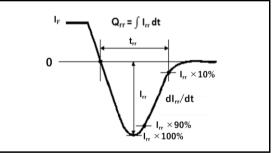


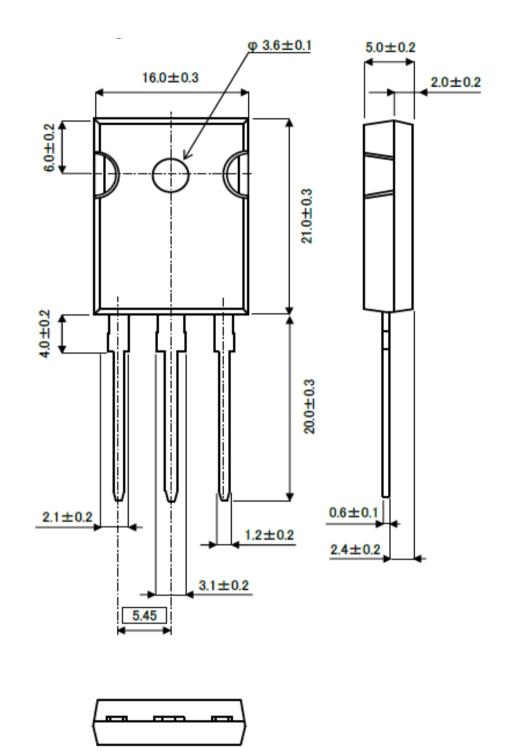
Fig.3-2 Reverse Recovery Waveform







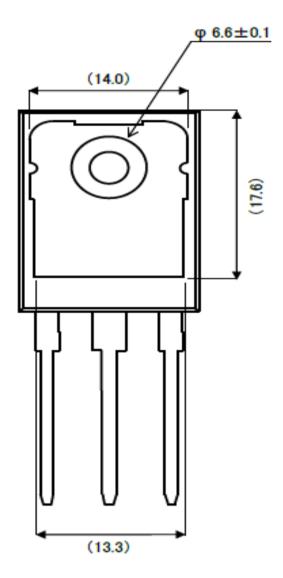
• Package Dimensions



Unit: mm





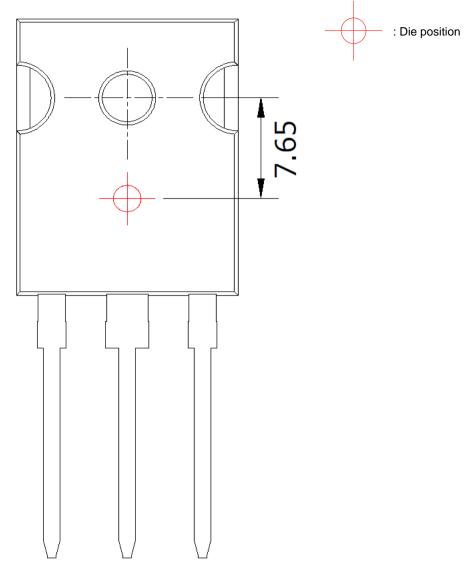


Unit: mm





Die Bonding Layout



•Front view of the packaging.

•Dimensions are design values.

·If the heat sink is to be installed, it should be in contact with the die bonding point.

Unit: mm





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